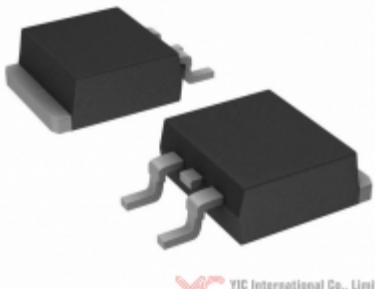

	<h2 style="color: red;">NTB65N02RT4G</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NTB65N02RT4G</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 25V 7.6A D2PAK
<b>Datenblätter:</b>	 <a href="#">NTB65N02RT4G.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 7479 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">NTB65N02RT4G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 25V 7.6A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	7479 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	1.04W (Ta), 62.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.6A (Tc)
Rds On (Max) @ Id, Vgs	8.2 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1330pF @ 20V
Verpackung	Tape & Reel (TR)



















































NTB65N02RT4G ist neu im Original, Suche NTB65N02RT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTB65N02RT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTB65N02RT4G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTB75N03</b> ON NTB75N03 ON</p>	 <p><b>NTB6448ANG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 80A D2PAK</p>	 <p><b>NTB65N02R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.6A D2PAK</p>	 <p><b>NTB75N03-006</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 75A D2PAK</p>
 <p><b>NTB6448ANT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 80A D2PAK</p>	 <p><b>NTB75N03-06T4G</b> VB NTB75N03-06T4G VB</p>	 <p><b>NTB65N02RG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.6A D2PAK</p>	 <p><b>NTB75N03-06T4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 75A D2PAK</p>

### heiße Teile

Mehr

 NTB5426NT4G	 NTB5605P	 NTB5605PG	 NTB5605PT4	 NTB5605PT4G
 NTB5605T4G	 NTB60N06	 NTB60N06G	 NTB60N06L	 NTB60N06LG
 NTB60N06LT4	 NTB60N06LT4G	 NTB60N06T4G	 NTB6410AN	 NTB6410ANG
 NTB6410ANT4G	 NTB6411AN	 NTB6411ANG	 NTB6411ANT4G	 NTB6412AN
 NTB6412ANG	 NTB6412ANT4G	 NTB6413AN	 NTB6413ANG	 NTB6413ANT4G
 NTB6448ANG	 NTB6448ANT4G	 NTB65N02RG	 NTB65N02RT4	 NTB75N03
 NTB75N03-06T4G	 NTB75N03-6G	 NTB75N03-6T4G	 NTB75N03L09G	 NTB75N03L09T4G
 NTB75N03RG	 NTB75N03RT4	 NTB75N03RT4G	 NTB75N06G	 NTB75N06LG
 NTB75N06LT4G	 NTB75N06T4G	 NTB85N03G	 NTB85N03T4	 NTB85N03T4G
 NTB90N02	 NTB90N02G	 NTB90N02T4	 NTB90N02T4G	 NTB90N03G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited